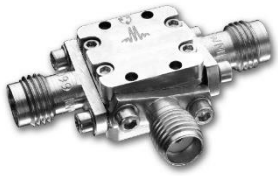
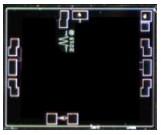
GaAs MMIC Triple Balanced Mixer

MM2-0530H

The MM2-0530H is a passive MMIC triple balanced mixer. It features a broadband IF port that spans from 2 to 20 GHz, and has excellent spurious suppression. GaAs MMIC technology improves upon the previous generation of hand assembled, hybrid M2 triple balanced mixers with improved isolations, unit-to-unit repeatability and reliability. The MM2-0530H is available as a wire bondable chip or connectorized SMA package. For a list of recommended LO driver amps for all mixers and IQ mixers, see here.





Features

- Broadband IF Port
- Typical Input 1 dB Compression of +15 dBm
- High Input IP3 of +21 dBm
- Excellent LO to IF Isolation
- Unit-to-Unit Repeatability
- RoHS Compliant

Electrical Specifications - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.
Specifications are shown for Configurations A (B). See page 2 for port locations.
All bare die are 100% DC tested and 100% visually inspected. RF testing is performed on a sample basis to verify conformance to datasheet guaranteed specifications.
Consult factory for more information.

Parameter	LO (GHz)	RF (GHz)	IF (GHz)	Min	Typ	Max	LO drive level (dBm)
Conversion Loss (dB) [1]	5-30	5-30	2-20		8 (9)		+20
Isolation (dB) LO-RF LO-IF RF-IF					See Plots		Config. A: + 15 to + 20 Config. B: + 14 to + 20
Input 1 dB Compression (dBm)					15 20		
Input Two-Tone Third Order Intercept Point (dBm)[2]					+ 21 + 28		

[1]Measured Conversion Loss measured at 3 GHz fixed IF

[2]IP3 depends on LO drive conditions, see plots for more details

Part Number Options

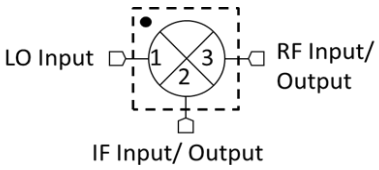
Please specify diode level and package style by adding to model number.

Package Styles		Examples		
Connectorized[1, 3]	S	MM2-0530HCH-2, MM2-0530HS		
Chip[2, 3] (RoHS)	CH-2	MM2-0530 (Model)	H (Diode Option)	S (Package)

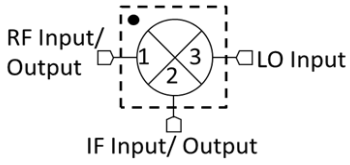
[1]Connectorized package consists of chip package wire bonded to a substrate, equivalent to an evaluation board.
[2]Chip package connects to external circuit through wire bondable gold pads.
[3]Note: For port locations and I/O designations, refer to the drawings on page 2 of this document.

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GaAs MMIC Triple Balanced Mixer MM2-0530H



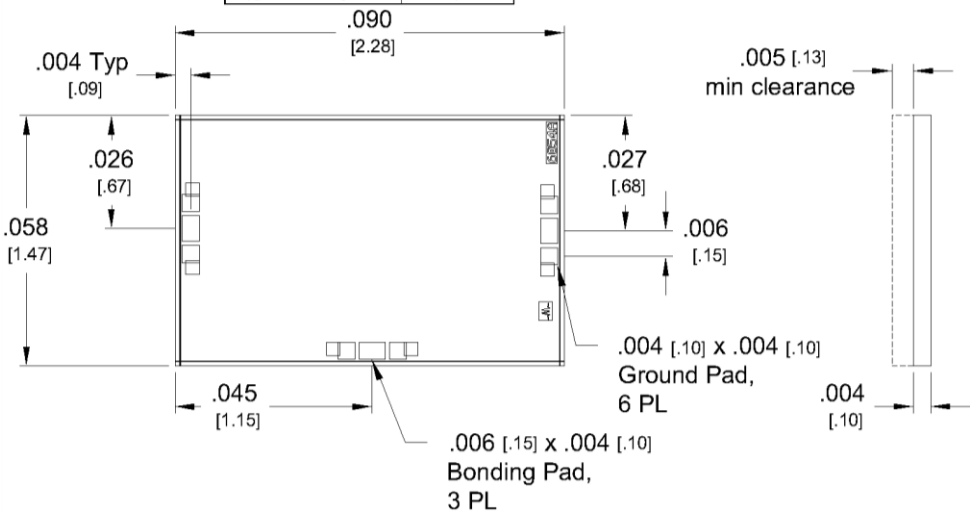
Configuration A



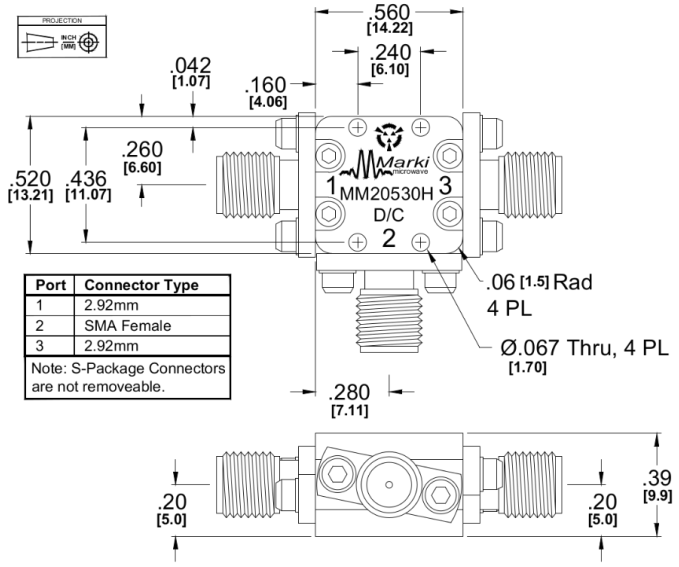
Configuration B

1. Configuration A/B refer to the same part number (MM2-0530H) used in one of two different ways for optimal spurious performance. For the lowest conversion loss, use the mixer in Configuration A (port 1 as the LO input, port 3 as the RF input or output). If you need to use a lower LO drive, use the mixer in Configuration B (port 1 as the RF input or output, port 3 as the LO input). For optimal spurious suppression, experimentation or simulation is required to choose between Configuration A and B. For more information, see here.

Function	Configuration A Port Number	Configuration B Port Number
LO	1	3
IF	2	2
RF	3	1



1. CH Substrate material is .004 thick GaAs.
2. I/O traces is 2 microns Au. Ground plane finish is 5 microns Au.
3. Wire Bonding - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

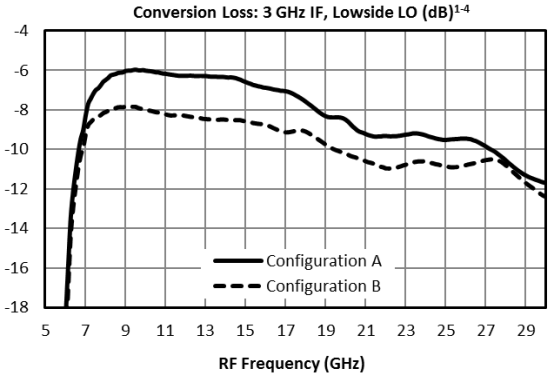


Port	Connector Type
1	2.92mm
2	SMA Female
3	2.92mm
Note: S-Package Connectors are not removeable.	

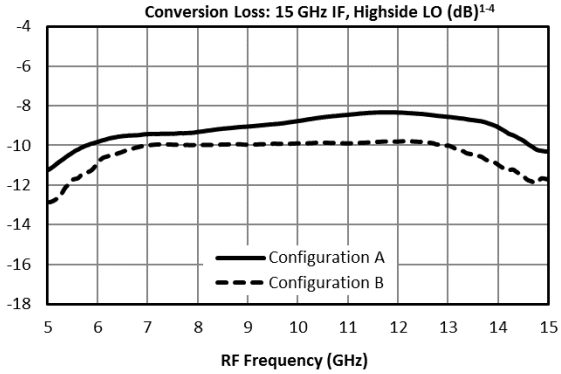
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Typical Performance

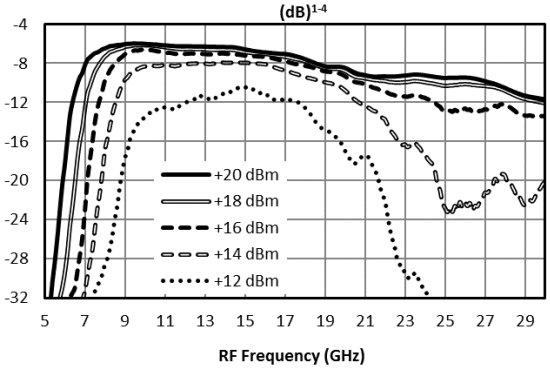
Conversion Loss: 3 GHz IF, Lowside LO (dB)[1-4]



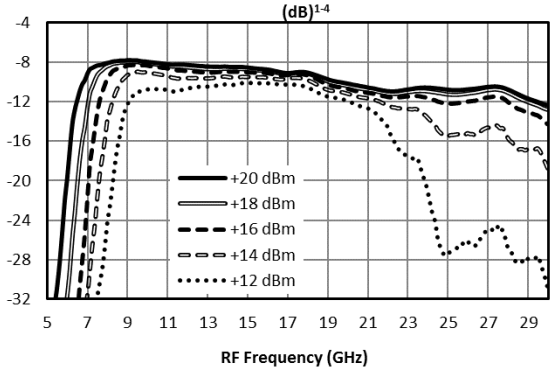
Conversion Loss: 15 GHz IF, Highside LO (dB)[1-4]



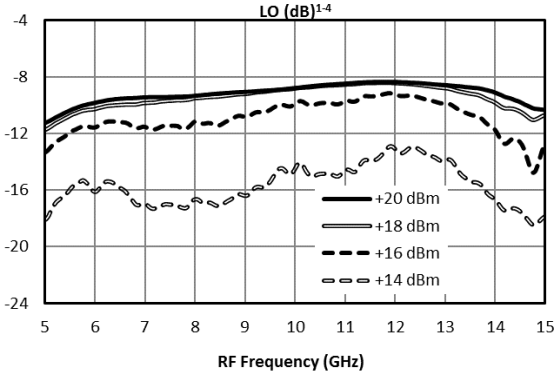
Configuration A Conversion Loss vs. LO Power: 3 GHz IF, Lowside LO (dB)[1-4]



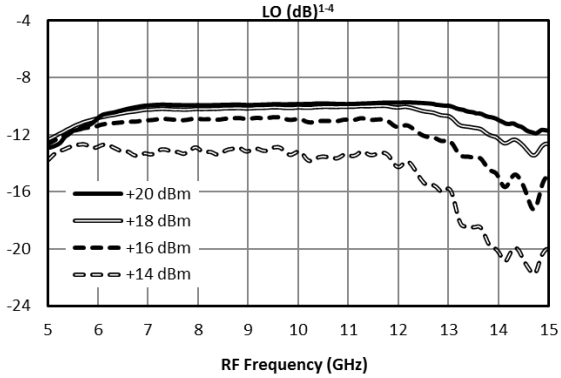
Configuration B Conversion Loss vs. LO Power: 3 GHz IF, Lowside LO (dB)[1-4]



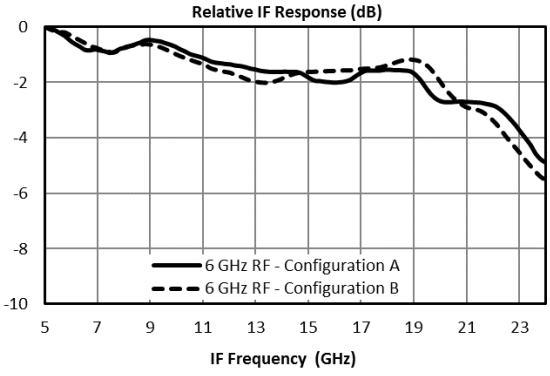
Configuration A Conversion Loss vs. LO Power: 15 GHz IF, Highside LO (dB)[1-4]



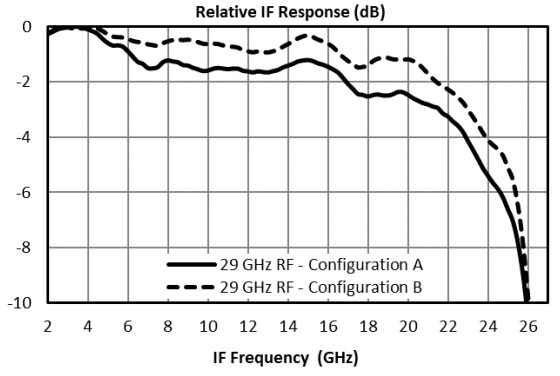
Configuration B Conversion Loss vs. LO Power: 15 GHz IF, Highside LO (dB)[1-4]



Relative IF Response (dB)

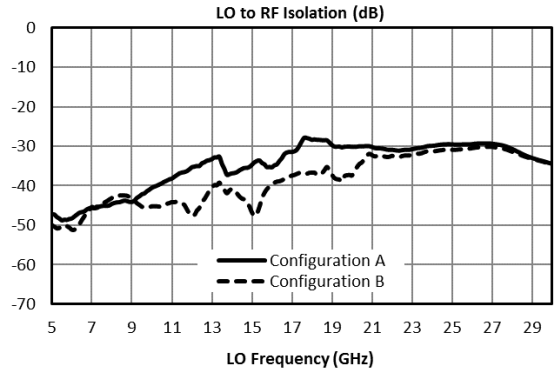


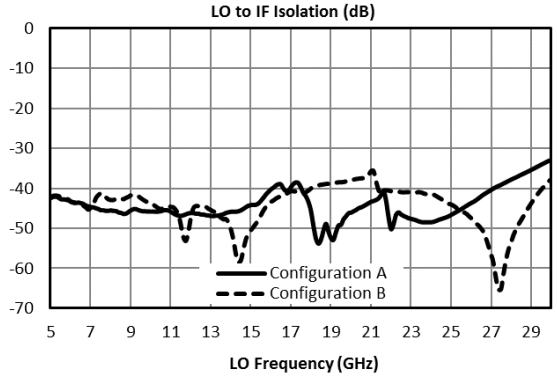
Relative IF Response (dB)

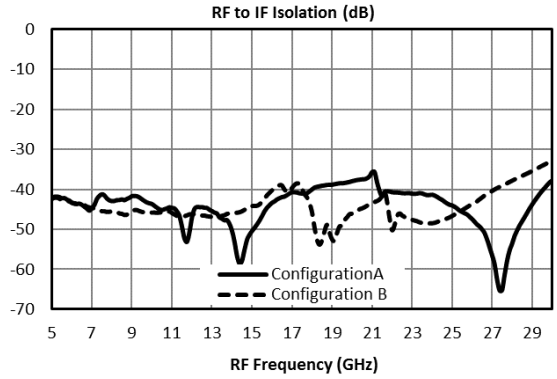


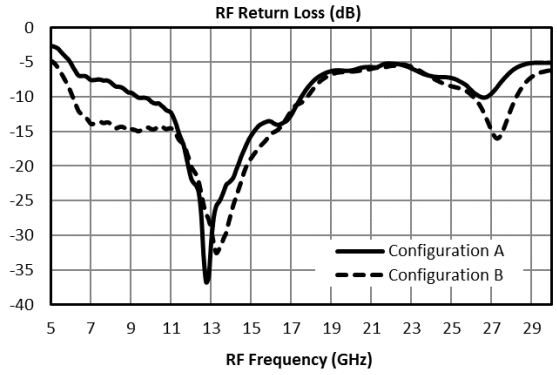
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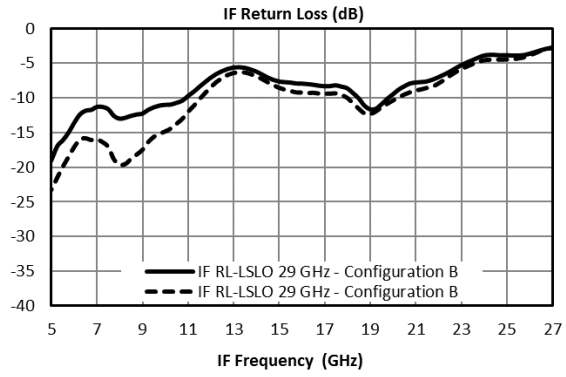
Typical Performance

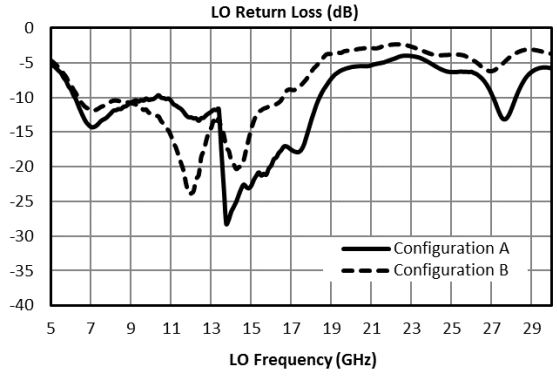








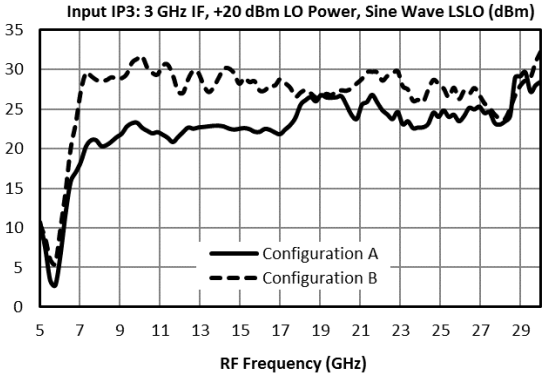




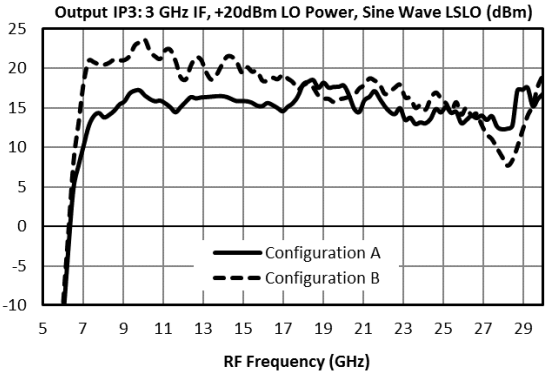
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Typical Performance

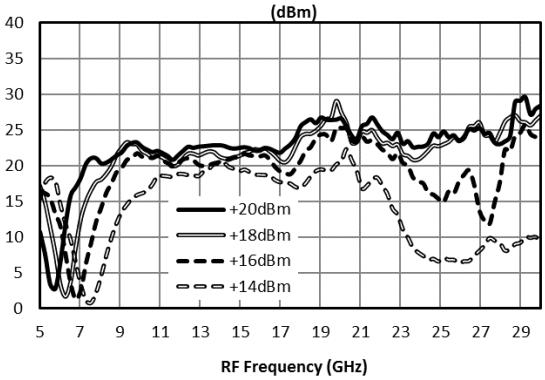
Input IP3: 3 GHz IF, +20 dBm LO Power, Sine Wave LSLO (dBm)



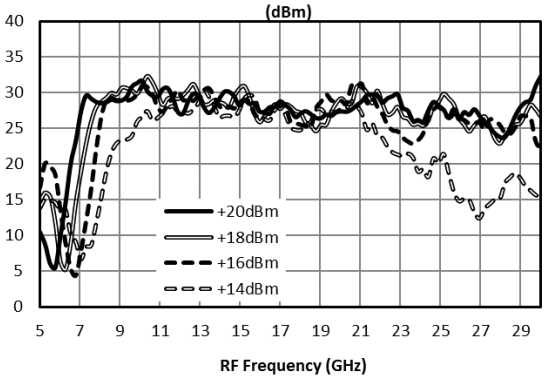
Output IP3: 3 GHz IF, +20dBm LO Power, Sine Wave LSLO (dBm)



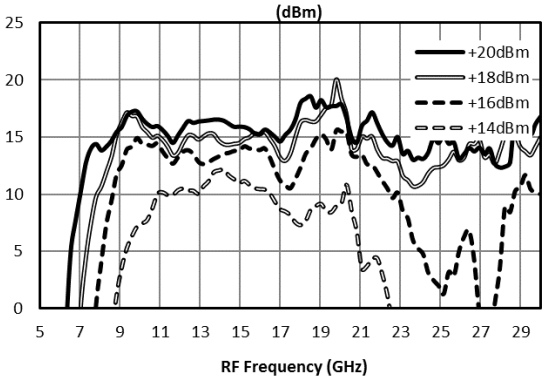
Configuration A Input IP3 vs LO Power: 3 GHz IF, Sine Wave LSLO (dBm)



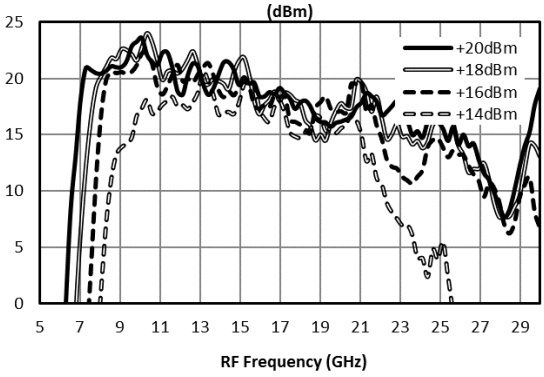
Configuration B Input IP3 vs LO Power: 3 GHz IF, Sine Wave LSLO (dBm)



Configuration A Output IP3 vs LO Power: 3 GHz IF, Sine Wave LSLO (dBm)

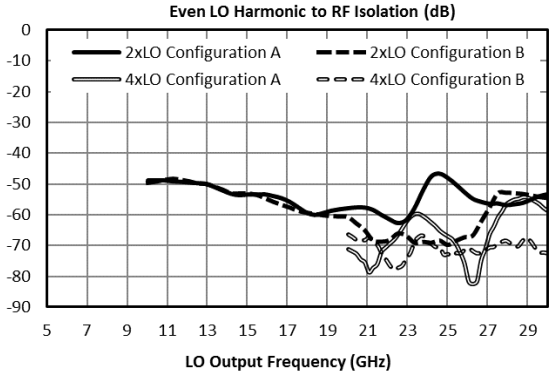


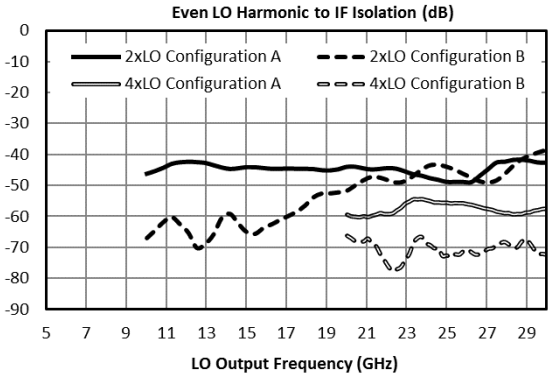
Configuration B Output IP3 vs LO Power: 3 GHz IF, Sine Wave LSLO (dBm)

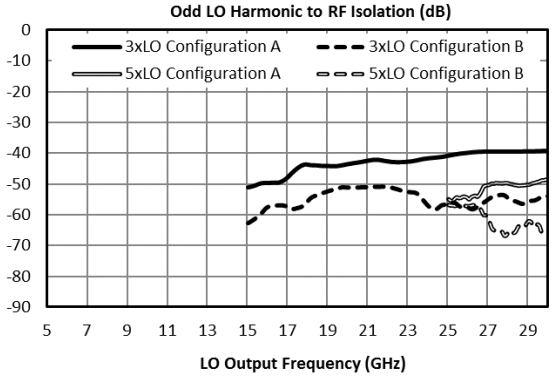


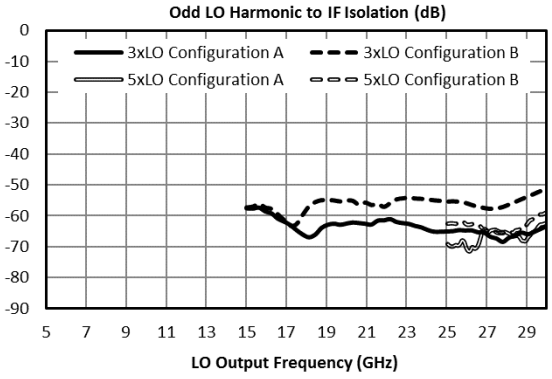
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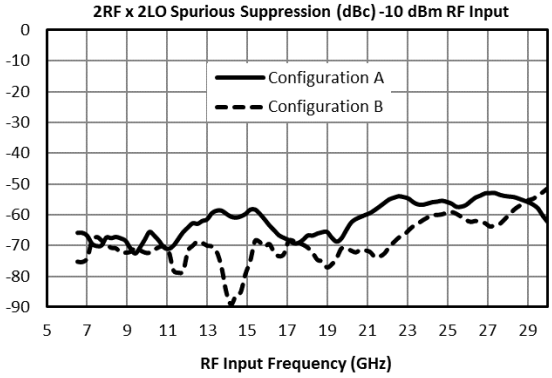
Typical Performance

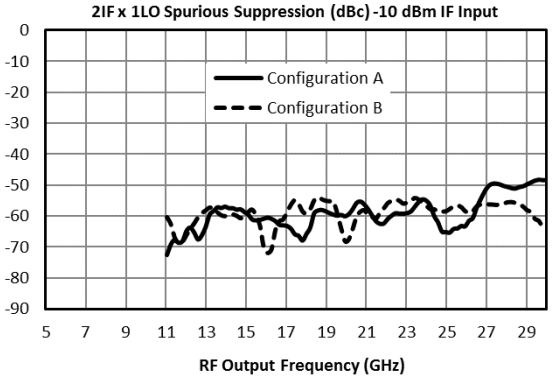












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Downconversion Spurious Suppression

Spurious data is taken by selecting RF and LO frequencies (±mLO±nRF) within the 5 to 30 GHz RF/LO bands, which create a 3 GHz IF spurious output. The mixer is swept across the full spurious band and the mean is calculated. The numbers shown in the table below are for a -10 dBm RF input. Spurious suppression is scaled for different RF power levels by (n-1), where "n" is the RF spur order. For example, the 2RFx2LO spur is 66 dBc for the A configuration for a -10 dBm input, so a -20 dBm RF input creates a spur that is (2-1) x (-10 dB) dB lower, or 76 dBc.

Typical Downconversion Spurious Suppression (dBc): A Configuration (B Configuration), Sine Wave LO [5]

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xRF	36 (33)	Reference	35 (43)	18 (27)	35 (42)	25 (35)
2xRF	70 (65)	66 (72)	62 (69)	66 (70)	68 (79)	75 (70)
3xRF	103 (105)	76 (111)	94 (122)	79 (105)	96 (123)	78 (106)
4xRF	N/A[6]	89 (162)	121 (155)	121 (156)	123 (155)	121 (156)
5xRF	N/A[6]	143 (181)	148 (181)	137 (180)	148 (182)	145 (180)

Upconversion Spurious Suppression

Spurious data is taken by mixing a 3 GHz IF with LO frequencies (±mLO±nIF), which creates an RF within the 5 to 30 GHz RF band. The mixer is swept across the full spurious output band and the mean is calculated. The numbers shown in the table below are for a -10 dBm IF input. Spurious suppression is scaled for different IF input power levels by (n-1), where "n" is the IF spur order. For example, the 2IFx1LO spur is typically 63 dBc for the A configuration for a -10 dBm input, so a -20 dBm IF input creates a spur that is (2-1) x (-10 dB) dB lower, or 73 dBc.

Typical Upconversion Spurious Suppression (dBc): A Configuration (B Configuration), Sine Wave LO [5]

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xIF	36 (39)	Reference	39 (42)	14 (13)	38 (39)	23 (28)
2xIF	83 (72)	59 (59)	65 (64)	68 (68)	75 (74)	67 (75)
3xIF	107 (108)	81 (82)	95 (98)	72 (86)	91 (103)	72 (85)
4xIF	131 (124)	119 (123)	123 (123)	130 (126)	127 (131)	121 (130)
5xIF	146 (164)	131 (140)	147 (151)	138 (147)	143 (152)	128 (153)

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Mounting and Bonding Recommendations

Marki MMICs should be attached directly to a ground plane with conductive epoxy. The ground plane electrical impedance should be as low as practically possible. This will prevent resonances and permit the best possible electrical performance. Datasheet performance is only guaranteed in an environment with a low electrical impedance ground.

Mounting - To epoxy the chip, apply a minimum amount of conductive epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip. Cure epoxy according to manufacturer instructions.

Wire Bonding - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

Circuit Considerations – 50 Ω transmission lines should be used for all high frequency connections in and out of the chip. Wirebonds should be kept as short as possible, with multiple wirebonds recommended for higher frequency connections to reduce parasitic inductance. In circumstances where the chip more than .001" thinner than the substrate, a heat spreading spacer tab is optional to further reduce bondwire length and parasitic inductance.

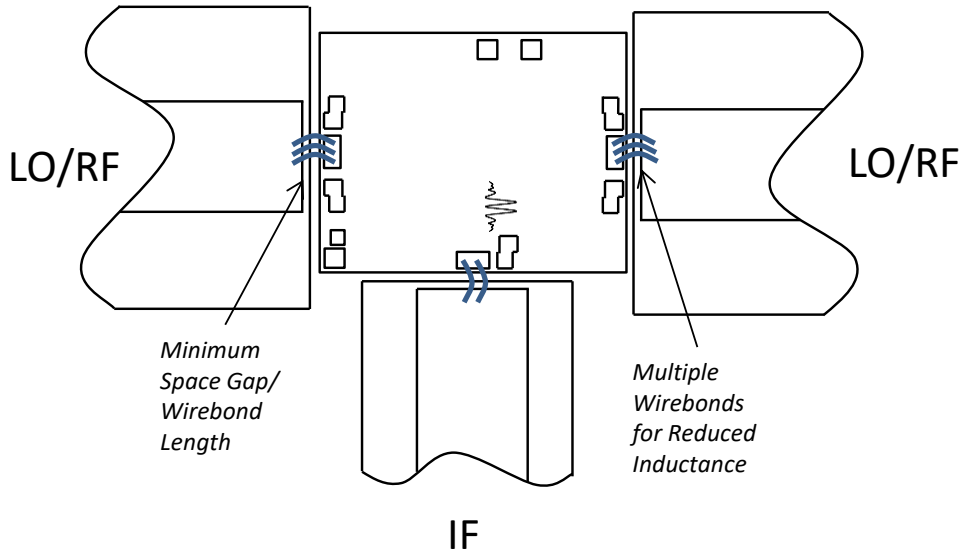
Handling Precautions

General Handling: Chips should be handled with a vacuum collet when possible, or with sharp tweezers using well trained personnel. The surface of the chip is fragile and should not be contacted if possible.

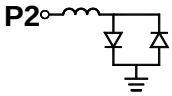
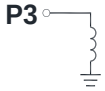
Static Sensitivity: GaAs MMIC devices are subject to static discharge, and should be handled, assembled, tested, and transported only in static protected environments.

Cleaning and Storage: Do not attempt to clean the chip with a liquid cleaning system or expose the bare chips to liquid. Once the ESD sensitive bags the chips are stored in are opened, chips should be stored in a dry nitrogen atmosphere.

Bonding Diagram



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Port	Description	DC Interface Schematic
Port 1	Port 1 is DC short and AC matched to 50 Ω from 5 to 30 GHz. Blocking capacitor is optional.	
Port 2	Port 2 is DC coupled to the diodes. Blocking capacitor is optional.	
Port 3	Port 3 is DC short and AC matched to 50 Ω from 5 to 30 GHz. Blocking capacitor is optional.	

Absolute Maximum Ratings	
Parameter	**Maximum Rating**
Port 1 DC Current	21 mA
Port 2 DC Current	15 mA
Port 3 DC Current	24 mA
RF Power Handling (RF+LO)	+ 28 dBm at +25°C, derated linearly to +20 dBm at +100°C
Operating Temperature	-55ºC to +100ºC
Storage Temperature	-65ºC to +125ºC

DATA SHEET NOTES:
1. Mixer Conversion Loss Plot IF frequency is 3 GHz unless otherwise specified.
2. Mixer Noise Figure typically measures within 0.5 dB of conversion loss for IF frequencies greater than 5 MHz.
3. Conversion Loss typically degrades less than 0.5 dB at +100°C and improves less than 0.5 dB at -55°C.
4. Unless otherwise specified, data is taken with +20 dBm LO drive.
5. Specifications are subject to change without notice. Contact Marki Microwave for the most recent specifications and data sheets.
6. Spurious suppression measurement is not valid; resulting IF is out of band.
7. Catalog mixer circuits are continually improved. Configuration control requires custom mixer model numbers and specifications.

Revision History

Revision Code	Revision Date	Comment
-	2016	Initial Release
A	November 2018	Correction to Port Designation Description
B	August 2019	Added ground pad dimensions on die

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www.markimicrowave.com

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